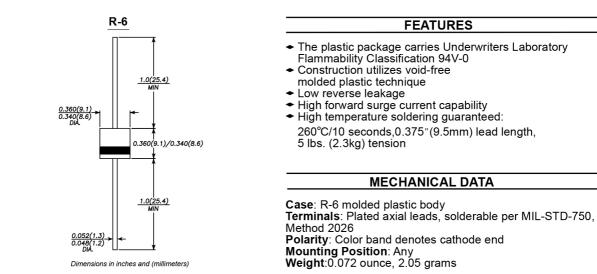


## 6A05 THRU 6A10

GENERAL PURPOSE SILICON RECTIFIER

Reverse Voltage - 50 to 1000 Volts Forward Current - 6.0 Amperes



## MAXIMUM RATINGS AND ELECTRICAL CHARACTERISTICS

Ratings at 25°C ambient temperature unless otherwise specified. Single phase half-wave 60Hz, resistive or inductive load for capacitive load current derate by 20%.

	SYMBOLS	6A05	6A1	6A2	6A4	6A6	6A8	6A10	UNITS
Maximum repetitive peak reverse voltage	Vrrm	50	100	200	400	600	800	1000	V
Maximum RMS voltage	Vrms	35	70	140	280	420	560	700	V
Maximum DC blocking voltage	Vdc	50	100	200	400	600	800	1000	V
Maximum average forward rectified current 0.375"(9.5mm) lead length at Ta=75°C	l(AV)	6.0							А
Peak forward surge current 8.3ms single half sine-wave superimposed on rated load (JEDEC Method)	Іғѕм	250							А
Maximum instantaneous forward voltage at 6.0A	Vf	1.0							V
Maximum DC reverse current Ta=25℃ at rated DC blocking voltage Ta=100℃	lr	10.0 400							μA
Typical junction capacitance (NOTE 1)	CJ	150						pF	
Typical thermal resistance (NOTE 2)	Reja	10.0						°C/W	
Operating junction and storage temperature range	TJ,TSTG	-55 to +150							°C

Note: 1. Measured at 1MHz and applied reverse voltage of 4.0V D.C.

2.Thermal resistance from junction to ambient at 0.375" (9.5mm)lead length, P.C.B. mounted

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200

100

10

0.1

0.5

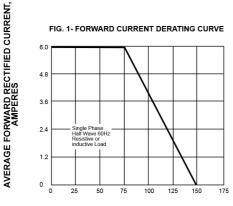
0.7

0.9

INSTANTANEOUS FORWARD VOLTAGE, VOLTS

INSTANTANEOUS FORWARD CURRENT, AMPERES

## **RATINGS AND CHARACTERISTIC CURVES 6A05 THRU 6A10**



AMBIENT TEMPERATURE,°C

TJ=25℃ PULSE WIDTH=300 μs 2%DUTY CYCLE

1.1

1.3 1.4

FIG. 3-TYPICAL INSTANTANEOUS FORWARD

CHARACTERISTICS

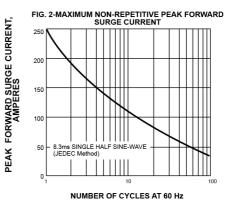
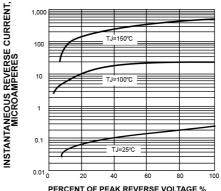
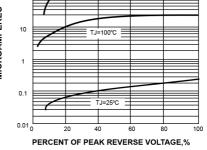
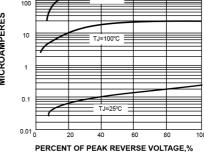


FIG. 4-TYPICAL REVERSE CHARACTERISTICS







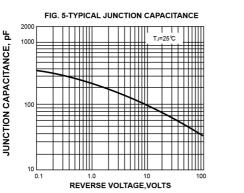
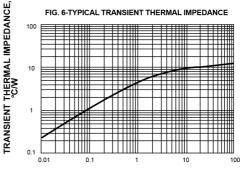


FIG. 6-TYPICAL TRANSIENT THERMAL IMPEDANCE



t, PULSE DURATION, sec.

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单击下面可查看定价,库存,交付和生命周期等信息

>>RCD(达标电子)